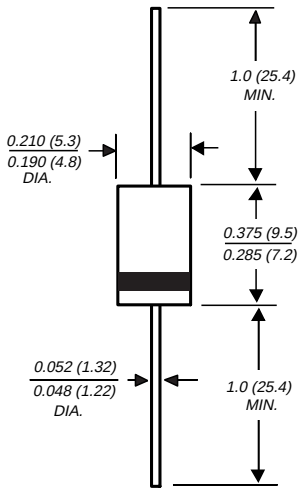
RGP30A THRU RGP30M

GLASS PASSIVATED JUNCTION FAST SWITCHING RECTIFIER

Reverse Voltage *- 50 to 1000 Volts* ***Forward Current*** *- 3.0 Amperes*

PATENTED*

DO-201AD

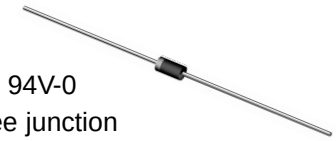


Dimensions in inches and (millimeters)

** Glass-plastic encapsulation technique is covered by Patent No. 3,996,602 and brazed-lead assembly by Patent No. 3,930,306*

SUPERECTIFIER®

FEATURES



- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Glass passivated cavity-free junction
- Capable of meeting environmental standards of MIL-S-19500
- High temperature metallurgically bonded construction
- 3.0 Ampere operation at T_A=55°C with no thermal runaway
- Typical I_R less than 0.2µA
- Fast switching for high efficiency
- High temperature soldering guaranteed 350°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

MECHANICAL DATA

Case: JEDEC DO-201AD molded plastic over glass body
Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
Polarity: Color band denotes cathode end
Mounting Position: Any
Weight: 0.04 ounce, 1.12 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

	SYMBOLS	RGP 30A	RGP 30B	RGP 30D	RGP 30G	RGP 30J	RGP 30K	RGP 30M	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	Volts
Maximum average forward rectified current 0.375" (9.5mm) lead length at T_A=55°C	$I_{(AV)}$	3.0							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	125.0							Amps
Maximum instantaneous forward voltage at 3.0A	V_F	1.3							Volts
Maximum DC reverse current T_A=25°C at rated DC blocking voltage T_A=125°C	I_R	5.0 100.0							µA
Maximum full load reverse current, full cycle average 0.375" (9.5mm) lead length at T_A=55°C	$I_{R(AV)}$	100.0							µA
Maximum reverse recovery time (NOTE 1)	t_{rr}	150				250	500		ns
Typical junction capacitance (NOTE 2)	C_J	60.0							pF
Typical thermal resistance (NOTE 3)	$R_{\Theta JA}$	20.0							°C/W
Operating junction and storage temperature range	T_J,T_{STG}	-65 to +175							°C

NOTES:
(1) Reverse recovery test conditions: I_F=0.5A, I_R=1.0A, I_{rr}=0.25A
(2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts
(3) Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

GENERAL SEMICONDUCTOR®

RATINGS AND CHARACTERISTIC CURVES RGP30A THRU RGP30M

FIG. 1 - FORWARD CURRENT DERATING CURVE

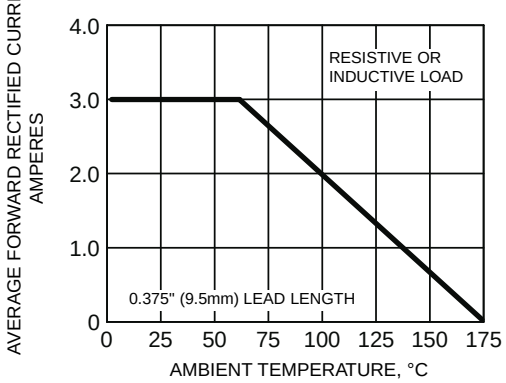


FIG. 2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

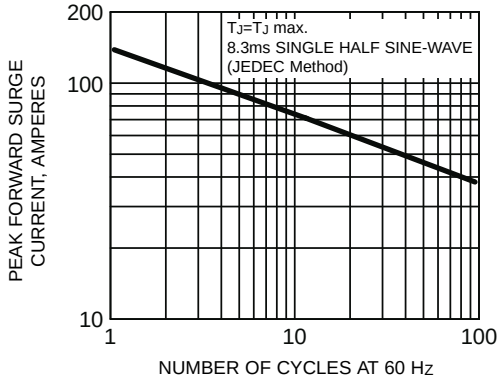


FIG. 3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

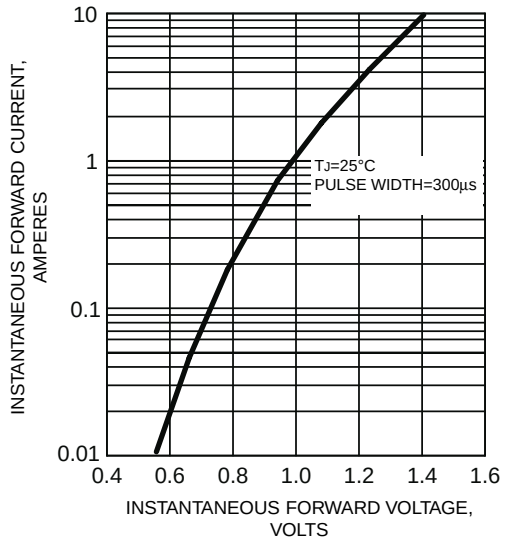


FIG. 4 - TYPICAL REVERSE CHARACTERISTICS

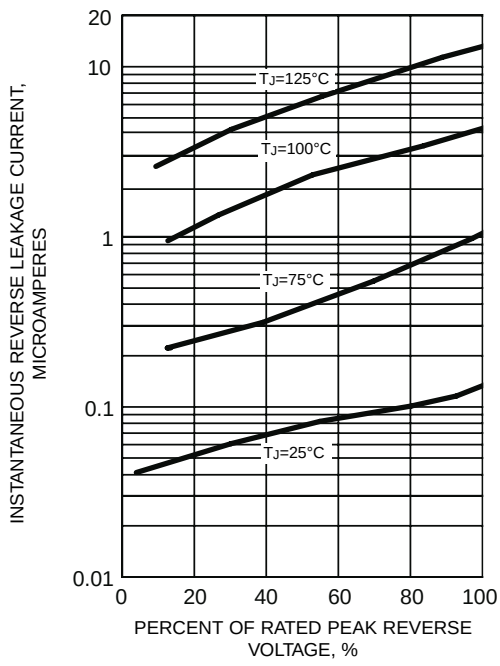
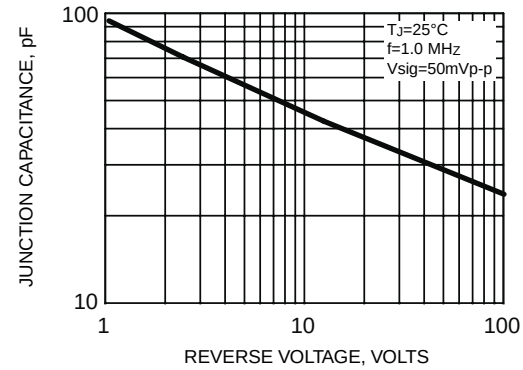


FIG. 5 - TYPICAL JUNCTION CAPACITANCE



GENERAL SEMICONDUCTOR®